

SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 30 - 100 V
CURRENT: 30 A

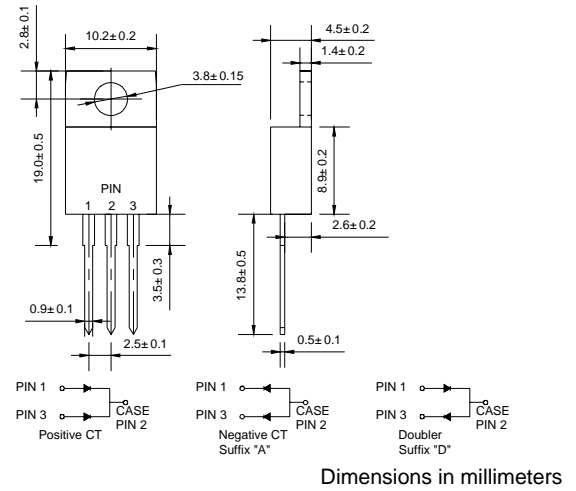
FEATURES

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

MECHANICAL DATA

- ◇ Case: JEDEC TO-220AB, molded plastic body
- ◇ Terminals: Solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.071ounce, 2.006 grams

TO-220AB



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		MBR 2530CT	MBR 2535CT	MBR 2540CT	MBR 2545CT	MBR 2550CT	MBR 2560CT	MBR 2580CT	MBR 25100CT	UNITS	
Maximum recurrent peak reverse voltage	V_{RRM}	30	35	40	45	50	60	80	100	V	
Maximum RMS Voltage	V_{RMS}	21	25	28	32	35	42	56	70	V	
Maximum DC blocking voltage	V_{DC}	30	35	40	45	50	60	80	100	V	
Maximum average forward total device rectified current @ $T_C = 130^\circ\text{C}$	$I_{F(AV)}$	30								A	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	150								A	
Maximum forward voltage (Note 1)	V_F	-				0.75	0.85		-		V
		-				0.65	-		-		
		0.82				-	-		-		
		0.73				-	-		-		
Maximum reverse current at rated DC blocking voltage	I_R	0.2				1.0				mA	
		40				50					
Maximum thermal resistance (Note2)	$R_{\theta JC}$	1.5								°C/W	
Operating junction temperature range	T_J	- 55 ---- + 150								°C	
Storage temperature range	T_{STG}	- 55 ---- + 150								°C	

NOTE: 1. Pulse test: 300µs pulse width, 1% duty cycle.

2. Thermal resistance from junction to case.

FIG.1 – PEAK FORWARD SURGE CURRENT

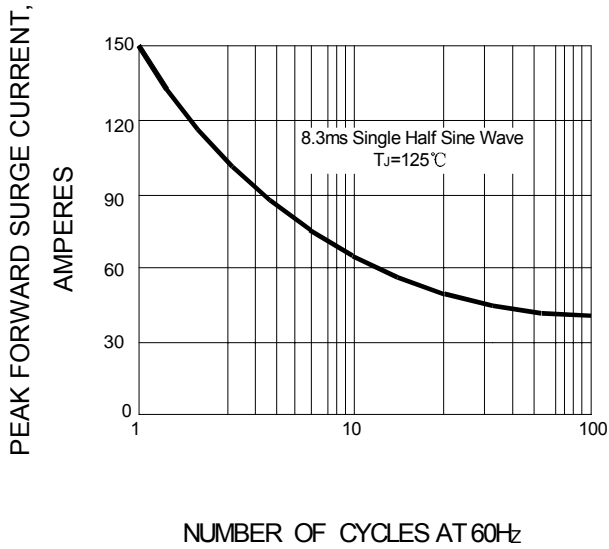


FIG.2 – FORWARD DERATING CURVE

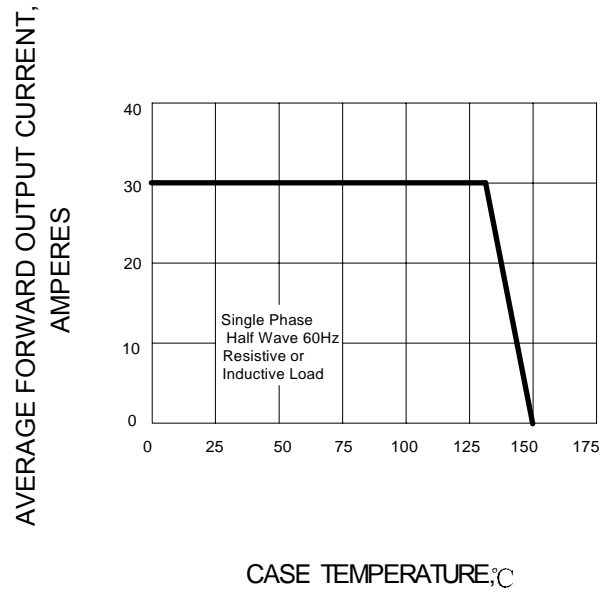


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

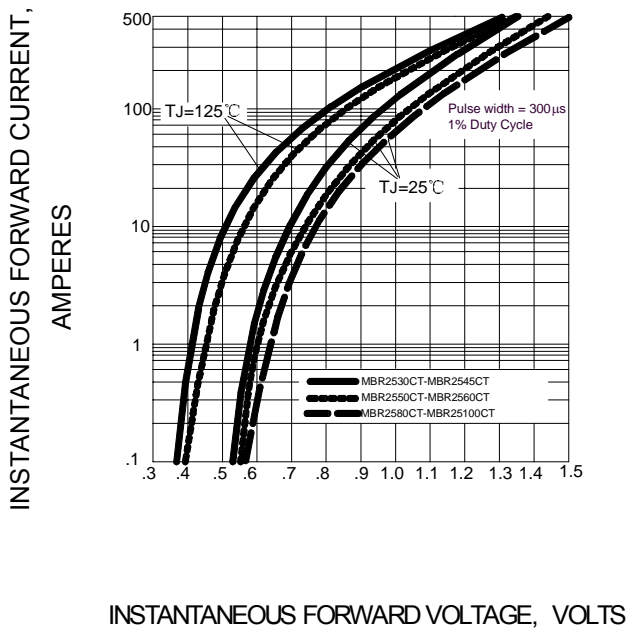


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

